



SEMICONDUCTOR

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

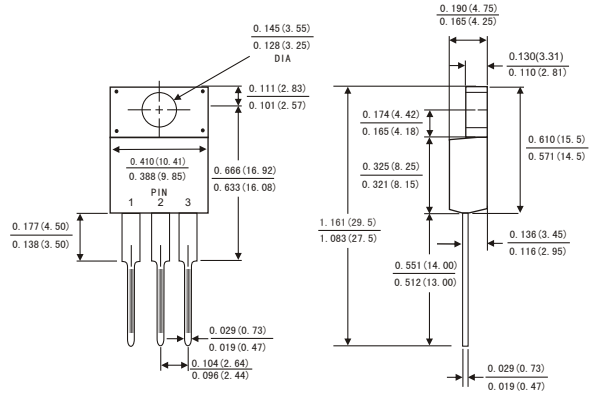
Forward Current - 10.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed:260° C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



ITO-220AB



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC ITO-220AB molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked.
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SRF 1020	SRF 1030	SRF 1040	SRF 1050	SRF 1060	SRF 1080	SRF 10A0	SRF 10150	SRF 10200	Units	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts	
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	Volts	
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts	
Maximum average forward rectified current (see Fig.1)	I _(AV)	10									Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150									Amps	
Maximum instantaneous forward voltage at 10.0 A(Note 1)	V _F	0.60			0.75		0.85		0.90	0.95	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	T _A = 25°C	0.5									mA
		T _A = 125°C	15			50						
Typical thermal resistance (Note 2)	R _{θJC}	2.5									°C/W	
Operating junction temperature range	T _J	-65 to +125				-65 to +150						°C
Storage temperature range	T _{STG}	-65 to +150									°C	

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SRF1020 THRU SRF10200

FIG.1-FORWARD CURRENT DERATING CURVE

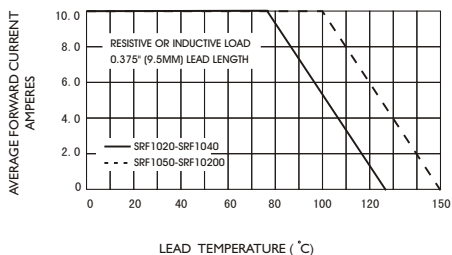


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

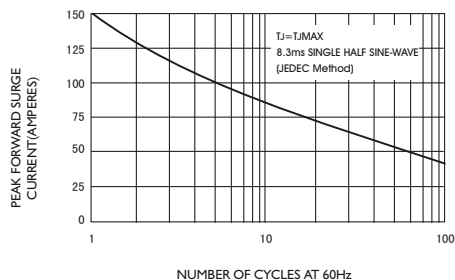


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

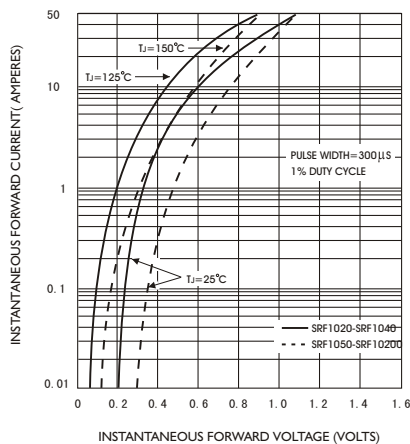


FIG.4-TYPICAL REVERSE CHARACTERISTICS

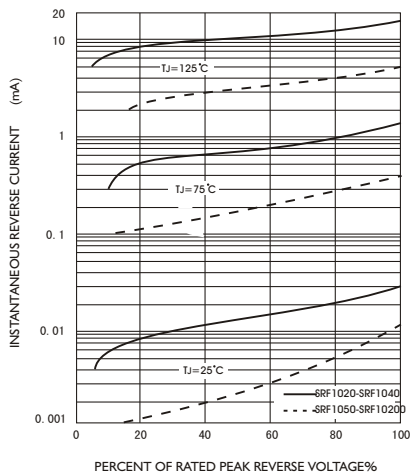


FIG.5-TYPICAL JUNCTION CAPACITANCE

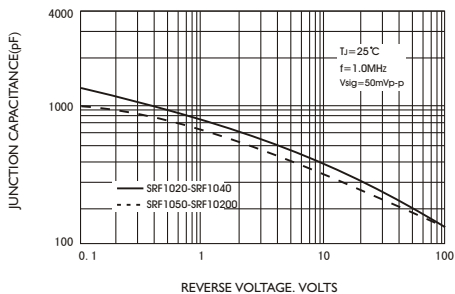


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

